

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re PATENT application of:)
Shunpei YAMAZAKI et al.) Art Unit: 2813
Serial No. 09/699,466) Examiner: Sarkar
Filed: 10/31/2000)
For: METHOD FOR FABRICATING A)
SEMICONDUCTOR DEVICE)

INFORMATION DISCLOSURE STATEMENT AND
NOTICE OF RELATED APPLICATION

Commissioner for Patents and Trademarks
Washington, D.C. 20231

Sir:

In accordance with the provisions of 37 C.F.R. 1.56 and 37 C.F.R. 1.97-1.99, it is requested that the reference(s) listed on the attached Form PTO-1449 be made of record in the above-identified application.

Copies of the references are submitted herewith in accordance with 37 C.F.R. 1.98(a). The requisite fee of \$180.00 is also submitted herewith in accordance with 37 C.F.R. 1.97(c).

The Examiner's attention is directed to US application Serial No. 08/205,298 (hereafter '298).

Japanese Patent Laid-Open Nos. 06-314785 and 06-314787 both correspond to the '298 application, and disclose that edge parts of an island-shaped silicon domain show a tapered profile with an angle in a range of 20 to 60 degrees, as described in Embodiment 4 of the '298 application.

The Commissioner is hereby authorized to charge fees under 37 C.F.R. 02/07/2002 00000004 09699466 §§1.16, 1.17, 1.20(a), 1.20(b), 1.20(c), and 1.20(d) (except the Issue Fee) which may 01 FC:126 be required now or hereafter, or credit any overpayment to Deposit Account No. 19-2380.

Respectfully submitted,

Luan C. Do
Reg. No. 38,434

NIXON PEABODY LLP
8180 Greensboro Drive, Suite 800
McLean, Virginia 22102
(703) 790-9110

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